

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	430	313/503,504,506,509.ccls. and (anode with (insulat\$3 dielectric)) and cathode and organic	US-PGPUB; USPAT	OR	OFF	2005/02/06 18:17
L2	188	313/503,504,506,509.ccls. and (anode with (insulat\$3 dielectric)) and cathode and organic and ((dielectric insulat\$3) with (thick thickness))	US-PGPUB; USPAT	OR	OFF	2005/02/06 19:10
L3	13	2 not @ad>"19970729"	US-PGPUB; USPAT	OR	OFF	2005/02/06 18:39
L4	208	313/503,504,506,509.ccls. and (anode with (oxide silicon carbon)) and cathode and organic and ((dielectric insulat\$3) with (thick thickness))	US-PGPUB; USPAT	OR	OFF	2005/02/06 19:00
L5	14	4 not @ad>"19970729"	US-PGPUB; USPAT	OR	OFF	2005/02/06 18:40
L7	61	428/690.ccls. and (anode with (oxide silicon carbon)) and cathode and organic and ((dielectric insulat\$3) with (thick thickness))	US-PGPUB; USPAT	OR	OFF	2005/02/06 18:40
L8	3	7 not @ad>"19970729"	US-PGPUB; USPAT	OR	OFF	2005/02/06 18:59
L9	52	("4356429" "4446399" "4539507" "4885211" "4924144" "5047687" "5059862" "5073446" "5276380" "5294869" "5294870" "5302468" "5306572" "5317169" "5374489" "5405709" "5508585" "5660573").PN. OR ("5902688").URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/06 18:51
L10	29	(313/502-509.ccls. 428/690.ccls. 427/66.ccls.) and (anode with (ZNO SNO VO NIO MoO)) and cathode and organic and ((dielectric insulat\$3) with (thick thickness))	US-PGPUB; USPAT	OR	OFF	2005/02/06 19:09
L11	0	(313/502-509.ccls. 428/690.ccls. 427/66.ccls.) and (anode with (ZNO SNO VO NIO MoO)) and cathode and organic and ((dielectric insulat\$3) with (thick thickness))	EPO; JPO; DERWENT	OR	OFF	2005/02/06 21:52
L12	3	(anode with (ZNO SNO VO NIO MoO)) and cathode and organic and ((dielectric insulat\$3) with (thick thickness))	EPO; JPO; DERWENT	OR	OFF	2005/02/06 19:10

L13	1457	(anode with (insulat\$3 dielectric) and cathode and organic and ((dielectric insulat\$3) with (thick thickness))	US-PGPUB; USPAT	OR	OFF	2005/02/06 19:10
L14	26	(anode with (insulat\$3 dielectric) and cathode and organic and ((dielectric insulat\$3) with (thick thickness))	EPO; JPO; DERWENT	OR	OFF	2005/02/06 20:16
L15	1	2000-372289.NRAN.	DERWENT	OR	OFF	2005/02/06 19:16
L16	5	"1224781"	EPO; JPO; DERWENT	OR	OFF	2005/02/06 19:18
L17	2	"11224781"	EPO; JPO; DERWENT	OR	OFF	2005/02/06 19:19
L18	1	1999-514270.NRAN.	DERWENT	OR	OFF	2005/02/06 19:18
L19	0	"20050023961"	EPO; JPO; DERWENT	OR	OFF	2005/02/06 19:20
L20	2	"6605823"	EPO; JPO; DERWENT	OR	OFF	2005/02/06 19:22
L21	1	1998-131030.NRAN.	DERWENT	OR	OFF	2005/02/06 19:20
L22	4	"6605823"	US-PGPUB; USPAT	OR	OFF	2005/02/06 19:22
L23	14	("5247190" "5317169" "5558904" "5747182" "5759709" "5766515" "5821002" "5965281" "5965901" "5969475" "5980781" "6002206" "6416885").PN. OR ("6605823").URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/06 19:22
L24	0	((positive near3 electrode) with (oxide carbon)) and cathode and organic and ((dielectric insulat\$3) with (thick thickness))	EPO; JPO; DERWENT	OR	OFF	2005/02/06 20:16
L25	42	((positive near3 electrode) with (oxide carbon)) and cathode and organic	EPO; JPO; DERWENT	OR	OFF	2005/02/06 20:18
L26	0	((positive near3 electrode) with (protect\$3 buffer insulat\$3 dielectric)) and cathode and organic and ((protect\$3 buffer insulat\$3 dielectric) with (oxide carbon))	EPO; JPO; DERWENT	OR	OFF	2005/02/06 20:19
L27	185	((positive near3 electrode) with (protect\$3 buffer insulat\$3 dielectric)) and cathode and organic and ((protect\$3 buffer insulat\$3 dielectric) with (oxide carbon))	US-PGPUB; USPAT	OR	OFF	2005/02/06 20:19

L28	3	((positive near3 electrode) with (protect\$3 buffer insulat\$3 dielectric)) and cathode and organic and ((protect\$3 buffer insulat\$3 dielectric) with (oxide carbon)) and (313/500-509.ccls. 428/690.ccls. 427/66.ccls.)	US-PGPUB; USPAT	OR	OFF	2005/02/06 20:25
L29	22	((positive near3 electrode) with (protect\$3 buffer insulat\$3 ((hole charge) near3 inject\$3) dielectric)) and cathode and organic and ((protect\$3 buffer insulat\$3 dielectric ((hole charge) near3 inject\$3)) with (oxide carbon)) and (313/500-509.ccls. 428/690.ccls. 427/66.ccls.)	US-PGPUB; USPAT	OR	OFF	2005/02/06 20:43
L30	1	"5710484".pn.	US-PGPUB; USPAT	OR	OFF	2005/02/06 20:34
L31	39	((positive near3 electrode) with (protect\$3 buffer semi\$conduct\$3 conduct\$3 ((hole charge) near3 inject\$3))) and cathode and organic and ((protect\$3 buffer semi\$conduct\$3 conduct\$3 ((hole charge) near3 inject\$3)) with (oxide carbon)) and (313/500-509.ccls. 428/690.ccls. 427/66.ccls.)	US-PGPUB; USPAT	OR	OFF	2005/02/06 20:45
L32	36	((positive near3 electrode) with (protect\$3 buffer semi\$conduct\$3 conduct\$3 ((hole charge) near3 inject\$3))) and cathode and organic and ((protect\$3 buffer semi\$conduct\$3 conduct\$3 ((hole charge) near3 inject\$3)) with (oxide Z?sub?O?sub?2 Sn?O?sub?2)) and (313/500-509.ccls. 428/690.ccls. 427/66.ccls.)	US-PGPUB; USPAT	OR	OFF	2005/02/06 20:52
L33	3	((positive near3 electrode) with (protect\$3 buffer semi\$conduct\$3 conduct\$3 ((hole charge) near3 inject\$3))) and cathode and organic and ((protect\$3 buffer semi\$conduct\$3 conduct\$3 ((hole charge) near3 inject\$3)) with oxide)	EPO; JPO; DERWENT	OR	OFF	2005/02/06 20:52
L34	144	((anode) with (protect\$3 buffer semi\$conduct\$3 conduct\$3 ((hole charge) near3 inject\$3))) and cathode and organic and ((protect\$3 buffer semi\$conduct\$3 conduct\$3 ((hole charge) near3 inject\$3)) with oxide)	EPO; JPO; DERWENT	OR	OFF	2005/02/06 20:52

L35	1174	((anode) with (protect\$3 buffer semi\$conduct\$3 conduct\$3 ((hole charge) near3 inject\$3))) and cathode and organic and ((protect\$3 buffer semi\$conduct\$3 conduct\$3 ((hole charge) near3 inject\$3)) with (oxide Z?sub?O?sub?2 Mo?O?sub?2 Sn?O?sub?2)) and (313/500-509. ccls. 428/690.ccls. 427/66.ccls.)	US-PGPUB; USPAT	OR	OFF	2005/02/06 20:53
L36	0	((anode) with (protect\$3 buffer semi\$conduct\$3 conduct\$3 ((hole charge) near3 inject\$3))) and cathode and organic and ((protect\$3 buffer semi\$conduct\$3 conduct\$3 ((hole charge) near3 inject\$3)) with (Z?sub?O?sub?2. Mo?O?sub?2 Sn?O?sub?2)) and (313/500-509.ccls. 428/690.ccls. 427/66.ccls.)	US-PGPUB; USPAT	OR	OFF	2005/02/06 20:54
L37	0	((anode) with (protect\$3 buffer semi\$conduct\$3 conduct\$3 ((hole charge) near3 inject\$3))) and cathode and organic and ((protect\$3 buffer semi\$conduct\$3 conduct\$3 ((hole charge) near3 inject\$3)) with ((Z?sub? near2 O?sub?2) (Mo near3 O?sub?2) (Sn near3 O?sub?2))) and (313/500-509.ccls. 428/690.ccls. 427/66.ccls.)	US-PGPUB; USPAT	OR	OFF	2005/02/06 20:55
L38	0	((anode).with (protect\$3 buffer semi\$conduct\$3 conduct\$3 ((hole charge) near3 inject\$3))) and cathode and organic and ((protect\$3 buffer semi\$conduct\$3 conduct\$3 ((hole charge) near3 inject\$3)) with ((Z near2 O?sub?2) (Mo near3 O?sub?2) (Sn near3 O?sub?2))) and (313/500-509 ccls. 428/690.ccls. 427/66.ccls.)	US-PGPUB; USPAT	OR	OFF	2005/02/06 20:55
L39	186	((anode) with (protect\$3 buffer semi\$conduct\$3 conduct\$3 ((hole charge) near3 inject\$3))) and cathode and organic and ((protect\$3 buffer semi\$conduct\$3 conduct\$3 ((hole charge) near3 inject\$3)) with (ZNO SNO NIO VO) and (313/500-509.ccls. 428/690. ccls. 427/66.ccls.)	US-PGPUB; USPAT	OR	OFF	2005/02/06 21:12
L40	2	"5981092"	EPO; JPO; DERWENT	OR	OFF	2005/02/06 21:12
L41	1	1997-542290.NRAN.	DERWENT	OR	OFF	2005/02/06 21:12

L42	0	(313/502-509.ccls. 428/690.ccls. 427/66.ccls.) and (anode with (insulat\$3 dielectric)) and cathode and organic and ((dielectric insulat\$3) with (thick thickness))	EPO; JPO; DERWENT	OR	OFF	2005/02/06 21:54
L43	26	(anode with (insulat\$3 dielectric)) and cathode and organic and ((dielectric insulat\$3) with (thick thickness))	EPO; JPO; DERWENT	OR	OFF	2005/02/06 21:52
L44	215	(313/502-509.ccls. 428/690.ccls. 427/66.ccls.) and (anode with (insulat\$3 dielectric)) and cathode and organic and ((dielectric insulat\$3) with (thick thickness))	US-PGPUB; USPAT	OR	OFF	2005/02/06 21:56